# NSN 5961-01-012-9311

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-012-9311

# Inclosure Material:

Metal

# **Overall Length:**

Between 0.240 inches and 0.260 inches

# **Terminal Length:**

1.500 inches

# **Overall Diameter:**

Between 0.335 inches and 0.370 inches

# Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-5

Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Terminal

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 4.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 0.50 amperes source cutoff current and 1.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

10.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Precious Material And Location:**

Eutetic die attachment gold

# **Precious Material:**

Gold

#### Test Data Document:

82577-928196 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# **Terminal Type And Quantity:**

3 uninsulated wire lead

# Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

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